BYG20D, BYG20G, BYG20J

Vishay General Semiconductor

Ultrafast Avalanche SMD Rectifier



www.vishay.com

DO-214AC (SMA)

1.5 A

200 V, 400 V, 600 V 30 A

1.0 µA

1.4 V

75 ns

20 mJ

150 °C

DO-214AC (SMA)

Single die

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

IFSM

 I_R

V_F at I_F

t_{rr}

 E_R

T_{.1} max.

Package

Diode variations

FEATURES

- Low profile package
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Low reverse current
- Soft recovery characteristics
- · Ultrafast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification of power supply, inverters, converters, and freewheeling diodes for consumer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AC (SMA) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	BYG20D BYG20G BYG20J			UNIT	
Device marking code		BYG20D	BYG20G	BYG20J		
Maximum repetitive peak reverse voltage	V _{RRM}	200 400 600			V	
Average forward current	I _{F(AV)}	1.5			A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30			А	
Pulse energy in avalanche mode, non repetitive (inductive load switch off) $I_{(BR)R} = 1 A, T_J = 25 \ ^{\circ}C$	E _R	20			mJ	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150			°C	

RoHS

COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	BYG20D	BYG20G	BYG20J	UNIT
Maximum instantaneous	I _F = 1 A	T _{.1} = 25 °C V _F ⁽¹⁾	1.3			V	
forward voltage	I _F = 1.5 A	1j=25 0	VF \	1.4			v
Maximum DC reverse current	V - V	T _J = 25 °C		1			μΑ
	$V_{\rm R} = V_{\rm RRM}$ $T_{\rm J} = 100 ^{\circ}{\rm C}$	T _J = 100 °C	I _R	10			
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	75		ns	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	BYG20D BYG20G BYG20J		BYG20J	UNIT	
Typical thermal resistance, junction to lead, $T_L = const.$	$R_{\theta JL}$	25		°C/W		
	R _{0JA} ⁽¹⁾	150				
Typical thermal resistance, junction to ambient	R _{0JA} ⁽²⁾	125		°C/W		
	R _{0JA} ⁽³⁾		100			

Notes

⁽¹⁾ Mounted on epoxy-glass hard tissue

 $^{(2)}\,$ Mounted on epoxy-glass hard tissue, 50 mm^2 35 μm Cu

 $^{(3)}$ Mounted on Al-oxide-ceramic (Al_2O_3), 50 mm^2 35 μm Cu

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
BYG20D-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel	
BYG20D-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel	
BYG20DHE3/TR ⁽¹⁾	0.064	TR	1800	7" diameter plastic tape and reel	
BYG20DHE3/TR3 ⁽¹⁾	0.064	TR3	7500	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

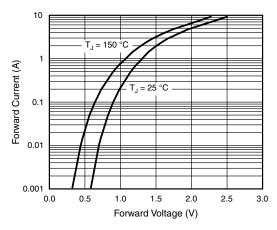


Fig. 1 - Forward Current vs. Forward Voltage

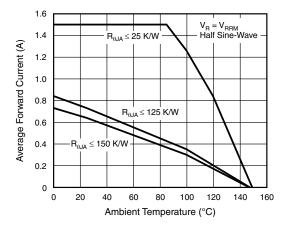


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

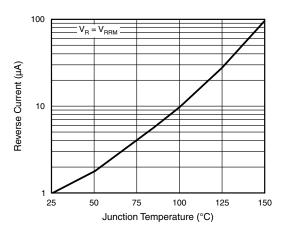


Fig. 3 - Reverse Current vs. Junction Temperature

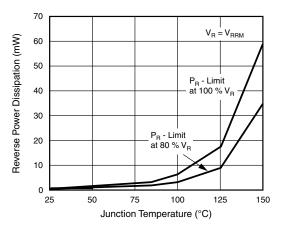


Fig. 4 - Max. Reverse Power Dissipation vs. Junction Temperature

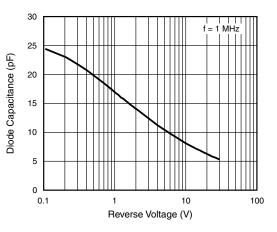


Fig. 5 - Diode Capacitance vs. Reverse Voltage

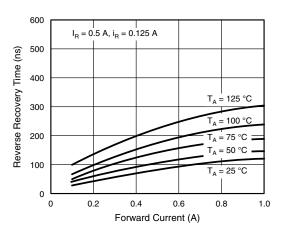


Fig. 6 - Reverse Recovery Time vs. Forward Current

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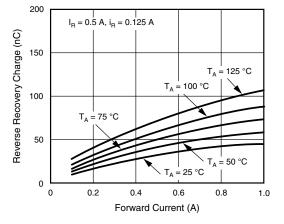


Fig. 7 - Reverse Recovery Charge vs. Forward Current

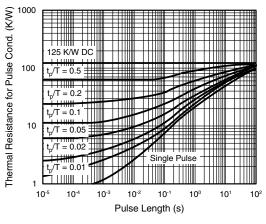
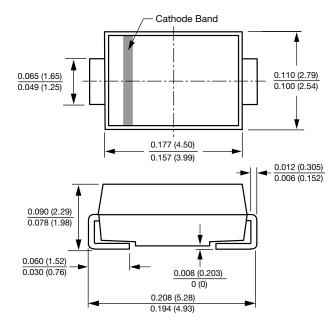
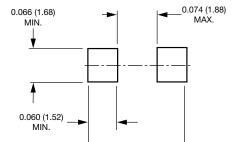


Fig. 8 - Thermal Response

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



DO-214AC (SMA)



0.208 (5.28) REF

Mounting Pad Layout

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